

NPN General Purpose Amplifier

This device is designed for general purpose amplifier applications at collector currents to 300 mA. Sourced from Process 33.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|-----------------------------------|--|-------------|-------|
| V _{CEO} | Collector-Emitter Voltage | 80 | V |
| V _{CBO} | Collector-Base Voltage | 80 | V |
| V _{EBO} | Emitter-Base Voltage | 4.0 | V |
| I _C | Collector Current - Continuous | 500 | mA |
| T _J , T _{stg} | Operating and Storage Junction Temperature Range | -55 to +150 | °C |

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

| Symbol | Characteristic | Мах | | | Units |
|---------------------|---|------------|------------|--------------|-------------|
| | | MPSA06 | *MMBTA06 | **PZTA06 | |
| PD | Total Device Dissipation Derate above 25°C | 625 5.0 | 350 2.8 | 1,000 8.0 | mW mW/°C |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case | 83.3 | | | °C/W |
| $R_{	ext{	heta}JA}$ | Thermal Resistance, Junction to Ambient | 200 | 357 | 125 | °C/W |

*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

** Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm².

NPN General Purpose Amplifier

(continued)

| Electrical Characteristics TA = 25°C unless otherwise noted | | | | | | |
|---|--------------------------------|--|-----|-----|-------|--|
| Symbol | I Parameter Test Conditions | | Min | Max | Units | |
| OFF CHAI | RACTERISTICS | $I_{\rm C} = 1.0$ mA, $I_{\rm B} = 0$ | 80 | 1 | V | |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | $I_E = 100 \ \mu A, I_C = 0$ | 4.0 | | V | |
| I _{CEO} | Collector-Cutoff Current | V _{CE} = 60 V, I _B = 0 | | 0.1 | μΑ | |
| CBO | Collector-Cutoff Current | $V_{CB} = 80 \text{ V}, I_{F} = 0$ | | 0.1 | μA | |

ON CHARACTERISTICS

| h _{FE} | DC Current Gain | $I_{C} = 10 \text{ mA}, V_{CE} = 1.0 \text{ V}$ $I_{C} = 100 \text{ mA}, V_{CE} = 1.0 \text{ V}$ | 100 100 | | |
|----------------------|--------------------------------------|---|------------|------|---|
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | $I_{\rm C} = 100 \text{ mA}, I_{\rm B} = 10 \text{ mA}$ | | 0.25 | V |
| V _{BE(on)} | Base-Emitter On Voltage | I_{C} = 100 mA, V_{CE} = 1.0 V | | 1.2 | V |

SMALL SIGNAL CHARACTERISTICS

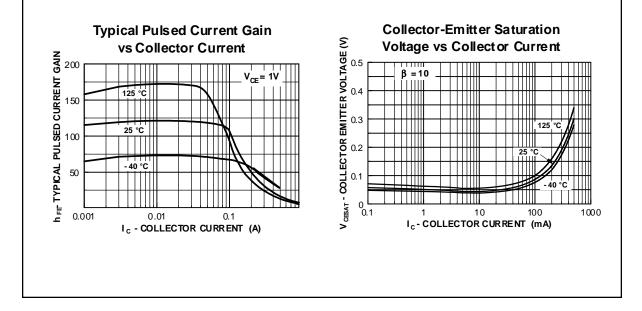
| f _T | Current Gain - Bandwidth Product | $I_{C} = 10 \text{ mA}, V_{CE} = 2.0 \text{ V},$ f = 100 MHz | 100 | | MHz |
|----------------|----------------------------------|---|-----|--|-----|
|----------------|----------------------------------|---|-----|--|-----|

*Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%

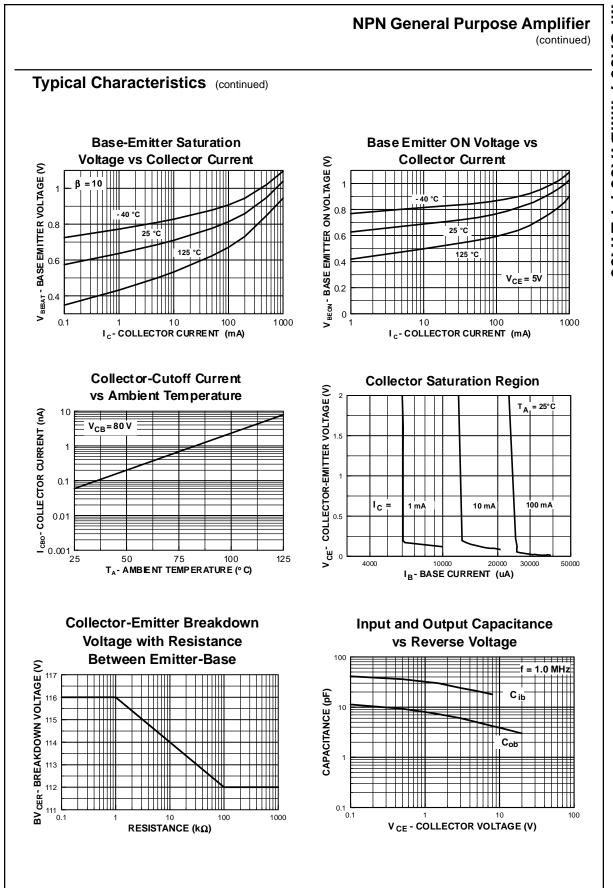
Spice Model

NPN (Is=8.324f Xti=3 Eg=1.11 Vaf=100 Bf=12.16K Ne=1.368 Ise=73.27f Ikf=.1096 Xtb=1.5 Br=11.1 Nc=2 Isc=0 Ikr=0 Rc=.25 Cjc=18.36p Mjc=.3843 Vjc=.75 Fc=.5 Cje=55.61p Mje=.3834 Vje=.75 Tr=72.15n Tf=516.1p Itf=.5 Vtf=4 Xtf=6 Rb=10)

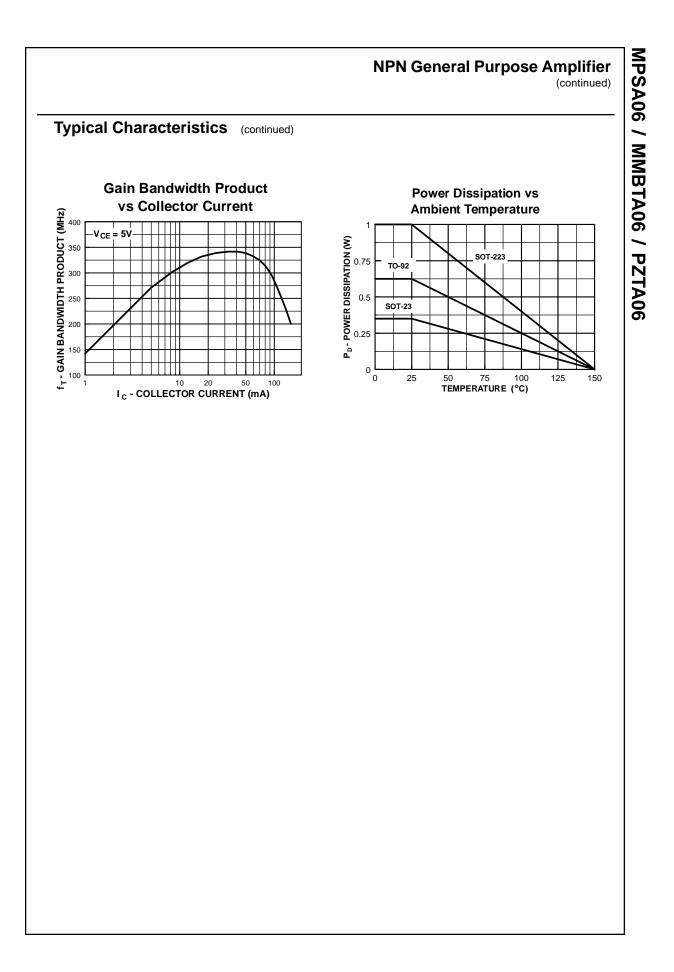
Typical Characteristics



MPSA06 / MMBTA06 / PZTA06



MPSA06 / MMBTA06 / PZTA06





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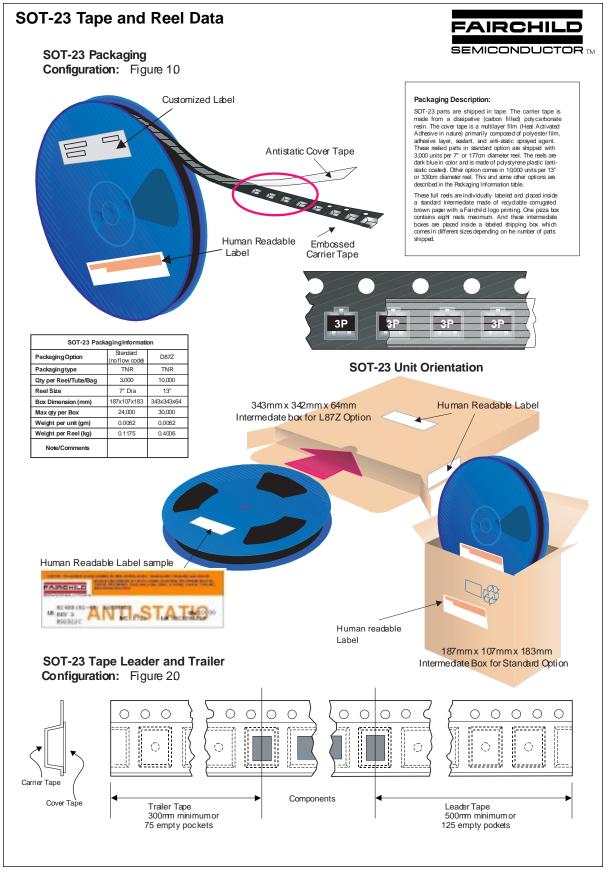
March 2001, Rev. B1





July 1999, Rev. A



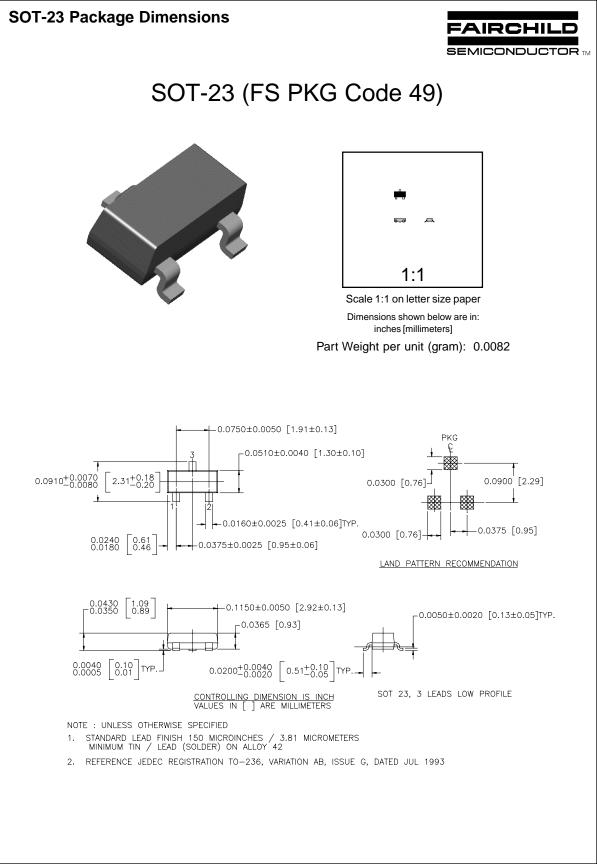


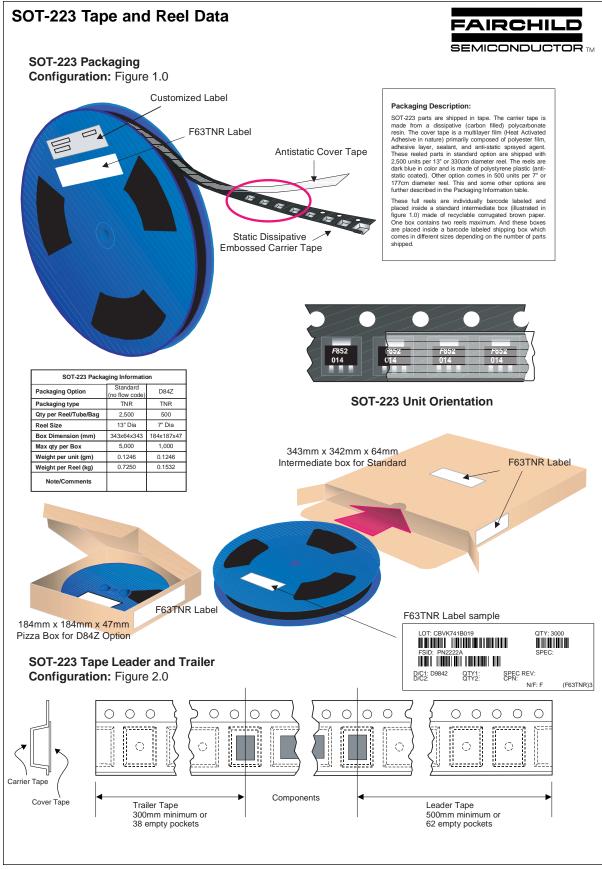
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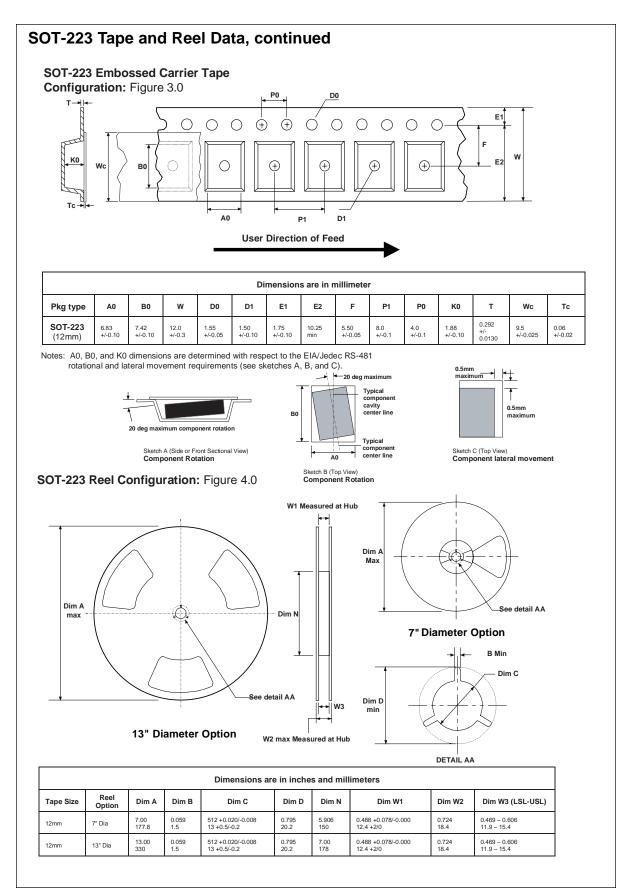
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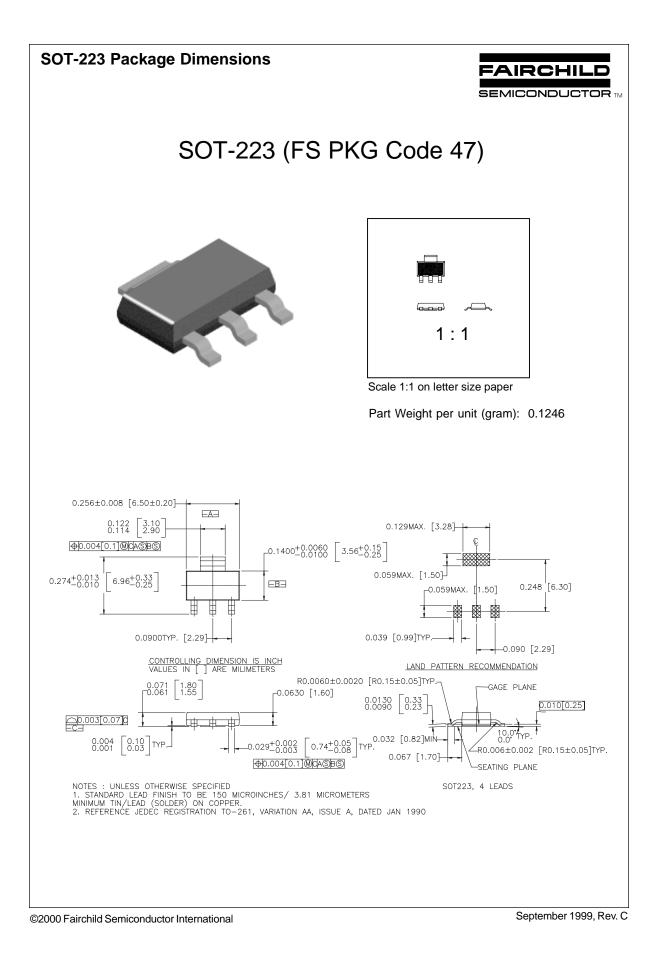




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|--------------------------|---------------------------|---|
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| | 1 | Rev G |